



MPE TEST REPORT

Applicant Quectel Wireless Solutions Co., Ltd
FCC ID XMR202006EC25AUX
Product LTE Module
Brand Quectel
Model EC25-AUX, EC25-AUX MINIPCIE
Report No. R2108A0762-M1
Issue Date October 18, 2021

TA Technology (Shanghai) Co., Ltd. tested the above equipment in accordance with the requirements in **FCC 47 CFR Part 1 1.1310**. The test results show that the equipment tested is capable of demonstrating compliance with the requirements as documented in this report.

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1 Test Laboratory

1.1 Notes of the Test Report

This report shall not be reproduced in full or partial, without the written approval of **TA technology (shanghai) co., Ltd.** The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein. Measurement Uncertainties were not taken into account and are published for informational purposes only. This report is written to support regulatory compliance of the applicable standards stated above.

1.2 Test facility

FCC (Designation number: CN1179, Test Firm Registration Number: 446626)

TA Technology (Shanghai) Co., Ltd. has been listed on the US Federal Communications Commission list of test facilities recognized to perform electromagnetic emissions measurements.



1.3 Testing Location

Company: TA Technology (Shanghai) Co., Ltd.
Address: No.145, Jintang Rd, Tangzhen Industry Park, Pudong Shanghai, China
City: Shanghai
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1.4 Laboratory Environment

Temperature	Min. = 18°C, Max. = 25 °C
Relative humidity	Min. = 30%, Max. = 70%
Ground system resistance	< 0.5 Ω
Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.	

2 Description of Equipment under Test

Client Information

Applicant	Quectel Wireless Solutions Co., Ltd
Applicant address	Building 5, Shanghai Business Park Phase III (Area B), No.1016 Tianlin Road, Minhang District, Shanghai, China 200233
Manufacturer	Quectel Wireless Solutions Co., Ltd
Manufacturer address	Building 5, Shanghai Business Park Phase III (Area B), No.1016 Tianlin Road, Minhang District, Shanghai, China 200233

General Technologies

Model	EC25-AUX, EC25-AUX MINIPCIE
IMEI	862708040005709
Hardware Version	R2.0
Software Version	EC25AUXGAR08A05M1G
Date of Testing:	May 12, 2020 ~ May 13, 2020

Note: 1. The EUT is sent from the applicant to TA and the information of the EUT is declared by the applicant.

2. All indications of Pass/Fail in this report are opinions expressed by TA Technology (Shanghai) Co., Ltd. based on interpretations and/or observations of test results. Measurement Uncertainties were not taken into account and are published for informational purposes only.

3. The series model number is: EC25-AUX MINIPCIE. The difference of these models are have different marketing requirement.

EC25-AUX, EC25-AUX MINIPCIE (Report No.: R2108A0762-M1) is a variant model of EC25-AUX, EC25-AUX MINIPCIE (Report No.: R2005A0269-M1V1). There is only changed the Power Amplifier, Software Version and Hardware Version of product. There is no test for variant in this report. The detailed product change description please refers to the *Difference Declaration Letter*.

3 Maximum conducted output power (measured)

Band		Burst Tune up Power(dBm)	Division Factors (dB)	Time-Averaged Tune up Power (dBm)
GSM 850	GSM	35.000	-9.03	25.97
GSM 1900	GSM	32.000	-9.03	22.97
Note: Division Factors To average the power, the division factor is as follows: 1Txslot = 1 transmit time slot out of 8 time slots => conducted power divided by (8/1) => -9.03 dB				

Band	Burst Tune up Power(dBm)	
	(dBm)	(mW)
GSM850	25.97	395.367
GSM1900	22.97	198.153
WCDMA II	25.00	316.228
WCDMA V	25.00	316.228
LTE Band 2	25.00	316.228
LTE Band 4	25.00	316.228
LTE Band 5	25.00	316.228
LTE Band 7	25.00	316.228

4 Test Result

According to section 1.1310 of FCC 47 CFR Part 1, limits for maximum permissible exposure (MPE) are as following

TABLE 1 – LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)

Frequency Range (MHz)	Electric Field Strength (V/m)	Magnetic Field Strength (A/m)	Power Density (mW/cm ²)	Averaging Time (minutes)
(A) Limits for Occupational/Controlled Exposures				
0.3-3.0	614	1.63	*(100)	6
3-30	1842/f	4.89/f	*(900/f ²)	6
30-300	61.4	0.163	1.0	6
300-1500			f/300	6
1500-100,000			5	6
(B) Limits for General Population/Uncontrolled Exposure				
0.3-1.34	614	1.63	*(100)	30
1.34-30	824/f	2.19/f	*(180/f ²)	30
30-300	27.5	0.073	0.2	30
300-1500			f/1500	30
1500-100,000			1.0	30

f = frequency in MHz

* = Plane-wave equivalent power density

Note1. Occupational/controlled limits apply in situations in which persons are exposed as a consequence of their employment provided those persons are fully aware of the potential for exposure and can exercise control over their exposure. Limits for occupational/controlled exposure also apply in situations when an individual is transient through a location where occupational / controlled limits apply provided he or she is made aware of the potential for exposure.

Note2: General population/uncontrolled exposures apply in situations in which the general public may be exposed, or in which persons that are exposed as a consequence of their employment may not be fully aware of the potential for exposure or can not exercise control over their exposure.

The maximum permissible exposure for 300~1500 MHz is f/1500, for 1500~100,000MHz is 1.0. So

Band	The maximum permissible exposure
GSM850	0.556mW/cm ²
GSM1900	1.000mW/cm ²
WCDMA II	1.000mW/cm ²
WCDMA V	0.556mW/cm ²
LTE Band 2	1.000mW/cm ²
LTE Band 4	1.000mW/cm ²
LTE Band 5	0.556mW/cm ²
LTE Band 7	1.000mW/cm ²

Band	Maximum Conducted Output Power (dBm)	EIRP limit (dBm)	Margin1 (dB)	Power density Limit		Margin2 (dB)	Final Margin (dB)
				(mW/cm ²)	(dBm)		
GSM850	25.970	40.600	14.630	0.566	34.541	8.571	8.571
GSM1900	22.970	33.000	10.030	1.000	37.013	14.043	10.030
WCDMA II	25.000	33.000	8.000	1.000	37.013	12.013	8.000
WCDMA V	25.000	40.600	15.600	0.566	34.541	9.541	9.541
LTE Band 2	25.000	33.000	8.000	1.000	37.013	12.013	8.000
LTE Band 4	25.000	30.000	5.000	1.000	37.013	12.013	5.000
LTE Band 5	25.000	40.600	15.600	0.566	34.541	9.541	9.541
LTE Band 7	25.000	33.000	8.000	1.000	37.013	12.013	8.000

Note: 1. The Maximum allowed antenna gain per Band should be less than or equal to the **Final Margin** which is the allowable maximum gain value to comply with limits for maximum permissible exposure (MPE).

2. The Final Margin is determined and selected to the worst-case of Margin1 and Margin2.

3. Margin1=EIRP Limit(dBm)-Maximum Conducted Power (dBm). EIRP limit reference standard part22/ part24/part27and part90 for each band, EIRP = ERP + 2.15 (dB).

4. Margin2=Power density Limit(dBm)-Maximum Conducted Power (dBm). Power density Limit(dBm): The max. obtained by MPE with 20cm.



IMPORTANT NOTE: To comply with the FCC RF exposure compliance requirements, the antenna(s) used for this transmitter must be installed to provide a separation distance of at least 20 cm from all persons and must not be co-located or operating in conjunction with any other antenna or transmitter. No change to the antenna or the device is permitted. Any change to the antenna or the device could result in the device exceeding the RF exposure requirements and void user's authority to operate the device.

**RF Exposure Calculations:**

The following information provides the minimum separation distance for the highest gain antenna provided. This calculation is based on the conducted power, considering maximum power and antenna gain. The formula shown in KDB 447498 D01 is used in the calculation.

Equation from KDB 447498 D01 General RF Exposure Guidance v06 (10/23/2015) is:

$$S = PG / 4\pi R^2$$

Where: S = power density (in appropriate units, e.g. mW/cm²)

P = Time-average maximum tune up procedure (in appropriate units, e.g., mW)

G = the numeric gain of the antenna

R = distance to the center of radiation of the antenna (20 cm = limit for MPE)

Band	PG (mW)	Test Result (mW/cm ²)	Limit Value (mW/cm ²)	Conclusion
GSM850	2845.116	0.566	0.566	Pass
GSM1900	1995.262	0.397	1.000	Pass
WCDMA II	1995.262	0.397	1.000	Pass
WCDMA V	2845.116	0.566	0.566	Pass
LTE Band 2	1995.262	0.397	1.000	Pass
LTE Band 4	1000.000	0.199	1.000	Pass
LTE Band 5	2845.116	0.566	0.566	Pass
LTE Band 7	1995.262	0.397	1.000	Pass
Note: R = 20cm π = 3.1416				

Note: For transmitters, minimum separation distance is 20cm, even if calculations indicate MPE distance is less.

*****END OF REPORT*****



ANNEX A: The EUT Appearance

The EUT Appearance are submitted separately.



ANNEX B: Product Change Description

The Product Change Description are submitted separately.